

<b>SANYO</b>	No.3575	<b>2SK1437</b>
		N-Channel MOS Silicon FET Very High-Speed Switching Applications

**Features**

- Low ON-state resistance.
- Very high-speed switching.
- Converters.

**Absolute Maximum Ratings at Ta = 25°C**

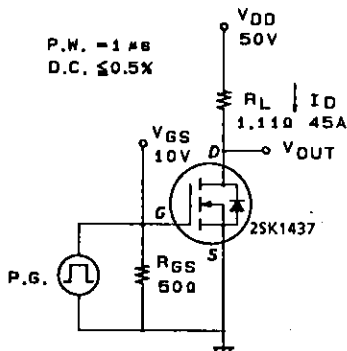
			unit
Drain to Source Voltage	V <sub>DSS</sub>	100	V
Gate to Source Voltage	V <sub>GSS</sub>	±20	V
Drain Current(DC)	I <sub>D</sub>	70	A
Drain Current(Pulse)	I <sub>DP</sub>	PW ≤ 10μs, duty cycle ≤ 1%	A
Allowable Power Dissipation	P <sub>D</sub>	Tc = 25°C	200 W
			3.5 W
Channel Temperature	T <sub>ch</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C

**Electrical Characteristics at Ta = 25°C**

			min	typ	max	unit
D-S Breakdown Voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 1mA, V <sub>GS</sub> = 0	100			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 100V, V <sub>GS</sub> = 0			100	μA
Gate to Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0			±100	nA
Cutoff Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1mA	1.5		2.5	V
Forward Transfer Admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10V, I <sub>D</sub> = 45A	40	65		S
Static Drain to Source on State Resistance	R <sub>DS(on)</sub>	I <sub>D</sub> = 45A, V <sub>GS</sub> = 10V	0.016	0.026		Ω
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 20V, f = 1MHz		7200		pF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 20V, f = 1MHz		2100		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	V <sub>DS</sub> = 20V, f = 1MHz		600		pF
Turn-ON Delay Time	t <sub>d(on)</sub>	I <sub>D</sub> = 45A, V <sub>GS</sub> = 10V V <sub>DD</sub> = 50V, R <sub>GS</sub> = 50Ω		80		ns
Rise Time	t <sub>r</sub>		270		ns	
Turn-OFF Delay Time	t <sub>d(off)</sub>		750		ns	
Fall Time	t <sub>f</sub>		350		ns	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> = 70A, V <sub>GS</sub> = 0			1.8	V

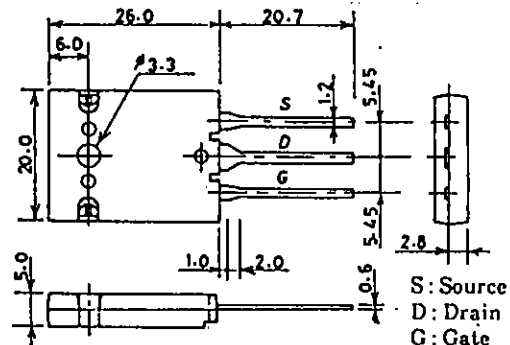
(Note) Be careful in handling the 2SK1437 because it has no protection diode between gate and source.

**Switching Time Test Circuit**

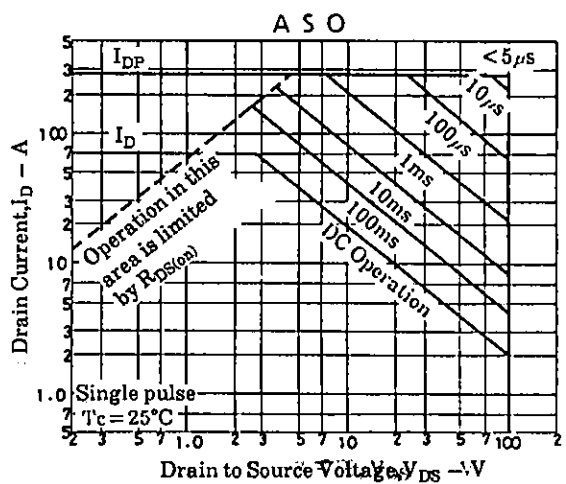
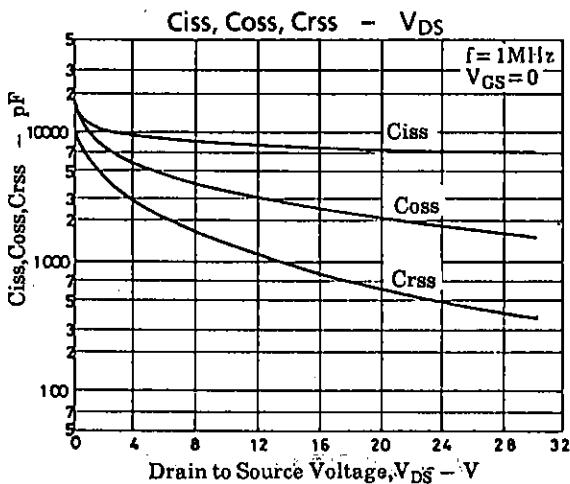
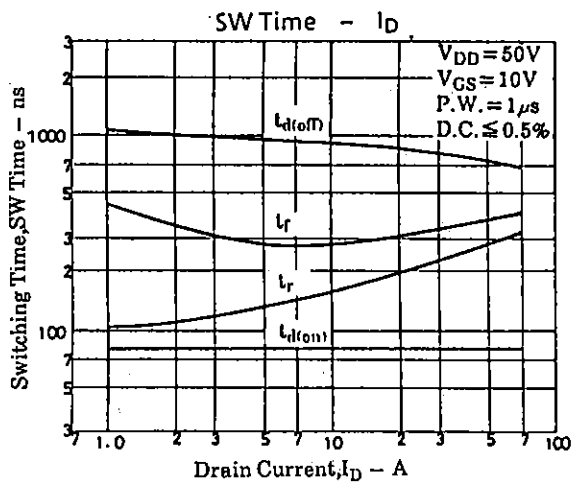
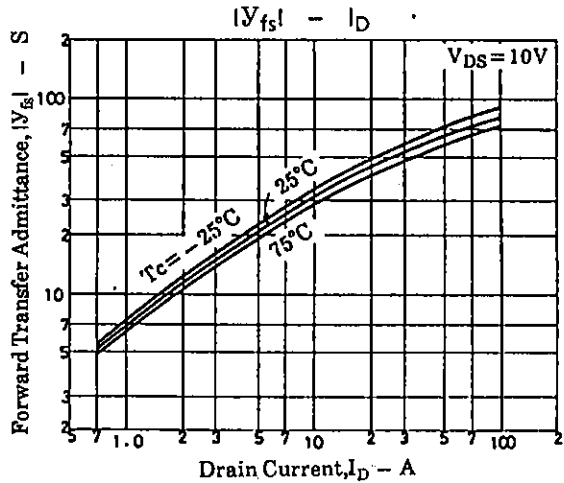
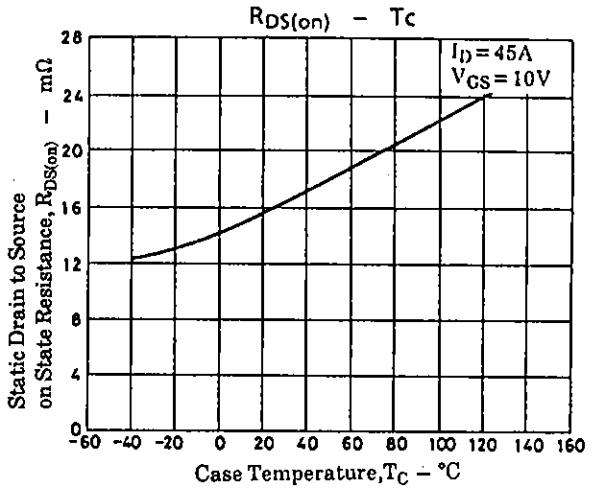
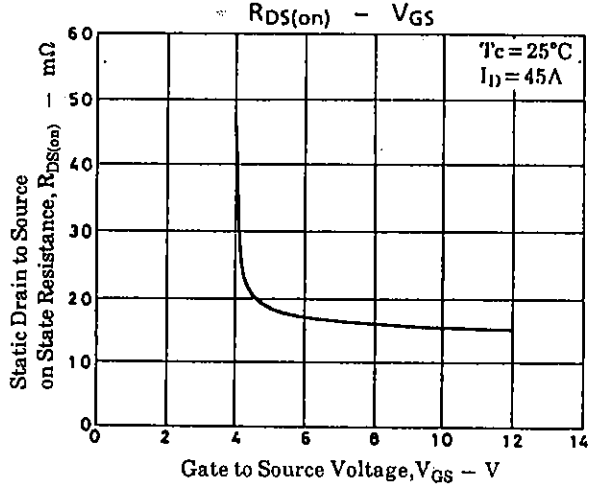
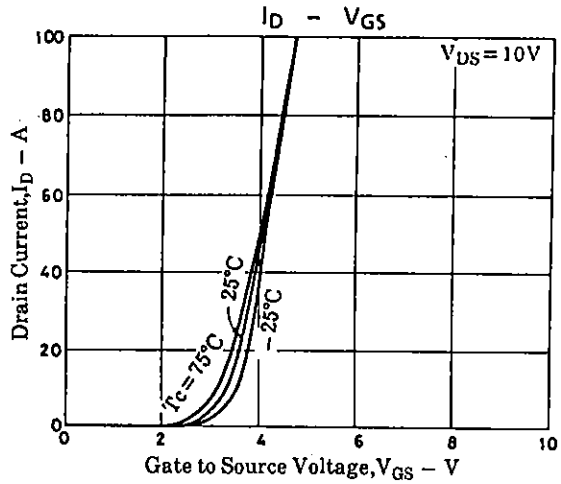
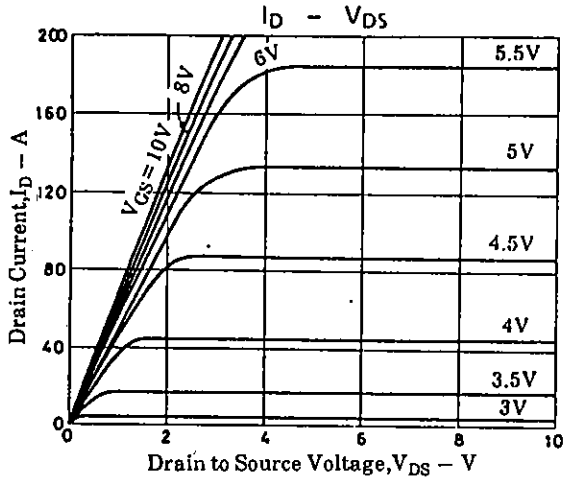


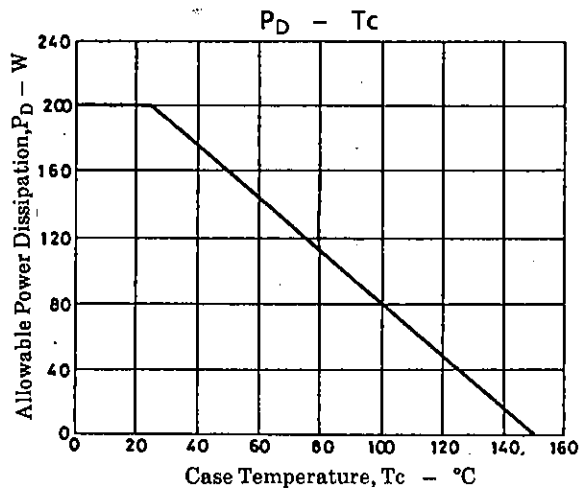
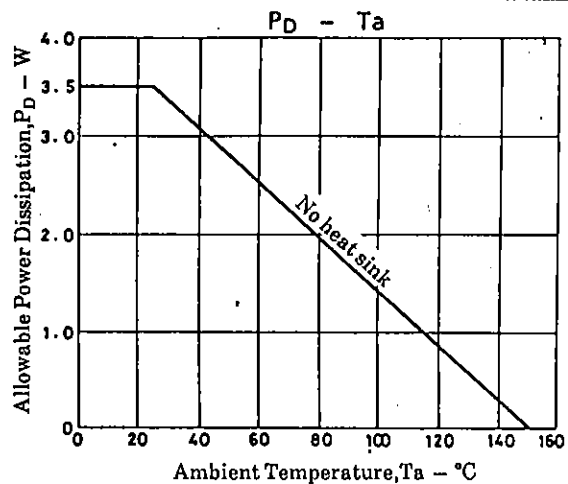
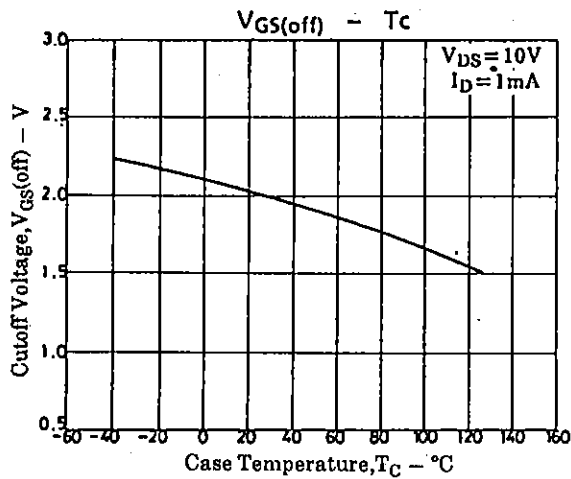
**Package Dimensions 2077**

(unit: mm)



SANYO: TO-3PBL





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